

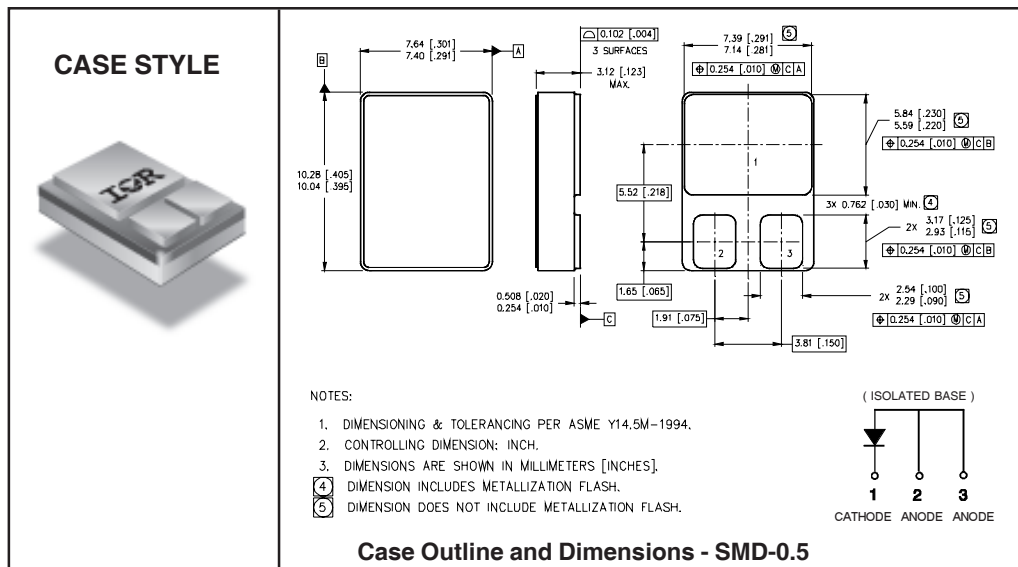
Major Ratings and Characteristics

Characteristics	1N7038U3	Units
$I_{F(AV)}$	30	A
V_{RRM}	150	V
I_{FSM} @ $t_p = 8.3ms$ half-sine	140	A
V_F @ 30Apk, $T_J = 125^\circ C$	0.92	V
T_J, T_{stg} Operating and storage	-65 to 150	$^\circ C$

Description/Features

The 1N7038U3 Schottky rectifier has been expressly designed to meet the rigorous requirements of high reliability environments. It is packaged in the hermetic surface mount SMD-0.5 ceramic package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source control drawings to TX, TXV and S quality levels.

- Hermetically Sealed
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long term Reliability
- Surface Mount
- Lightweight
- ESD Rating: Class 1B per MIL-STD-750, Method 1020



Voltage Ratings

Part number	1N7038U3
V_R Max. DC Reverse Voltage (V)	150
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	Limits	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current See Fig. 5	30	A	50% duty cycle @ $T_C = 83^\circ\text{C}$, square waveform
I_{FSM} Max. Peak One Cycle Non - Repetitive Surge Current	140	A	@ $t_p = 8.3\text{ms}$ half-sine

Electrical Specifications

Parameters	Limits	Units	Conditions
V_{FM} Max. Forward Voltage Drop See Fig. 1①	1.07	V	@15A $T_J = -55^\circ\text{C}$ ②
	1.26	V	@30A
	0.96	V	@15A $T_J = 25^\circ\text{C}$ ②
	1.18	V	@30A
	0.75	V	@15A $T_J = 125^\circ\text{C}$ ②
	0.92	V	@30A
I_{RM} Max. Reverse Leakage Current See Fig. 2①	0.12	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	6.0	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	340	pF	$V_R = 5V_{DC}$ (1MHz, 25°C)
L_S Typical Series Inductance	4.8	nH	Measured from center of cathode pad to center of anode pad

Thermal-Mechanical Specifications

Parameters	Limits	Units	Conditions
T_J Max. Junction Temperature Range	-65 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance, Junction to Case	1.82	$^\circ\text{C}/\text{W}$	DC operation See Fig. 4
wt Weight (Typical)	1.0	g	
Die Size (Typical)	125X125	mils	
Case Style	SMD-0.5		

① Pulse Width < 300 μs , Duty Cycle < 2%

② Pins 2 and 3 externally tied together

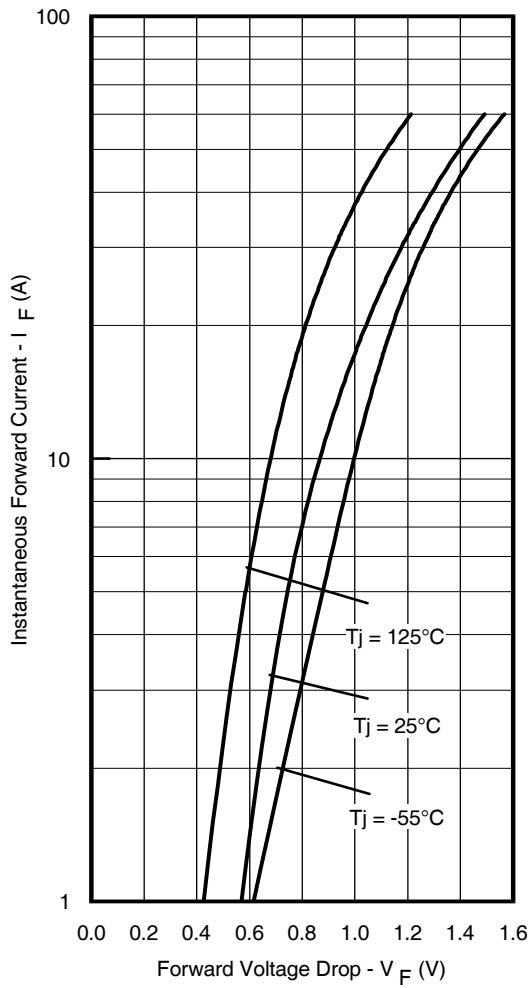


Fig. 1 - Max. Forward Voltage Drop Characteristics

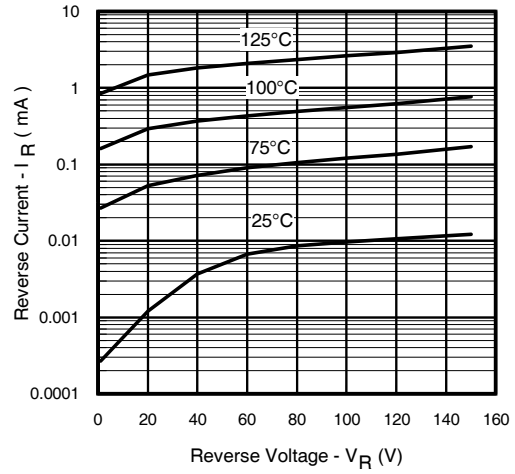


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

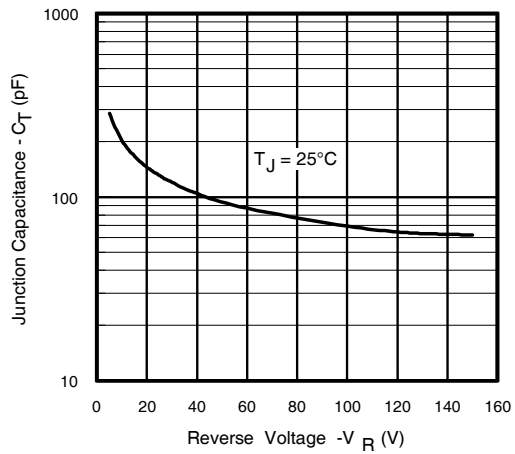


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

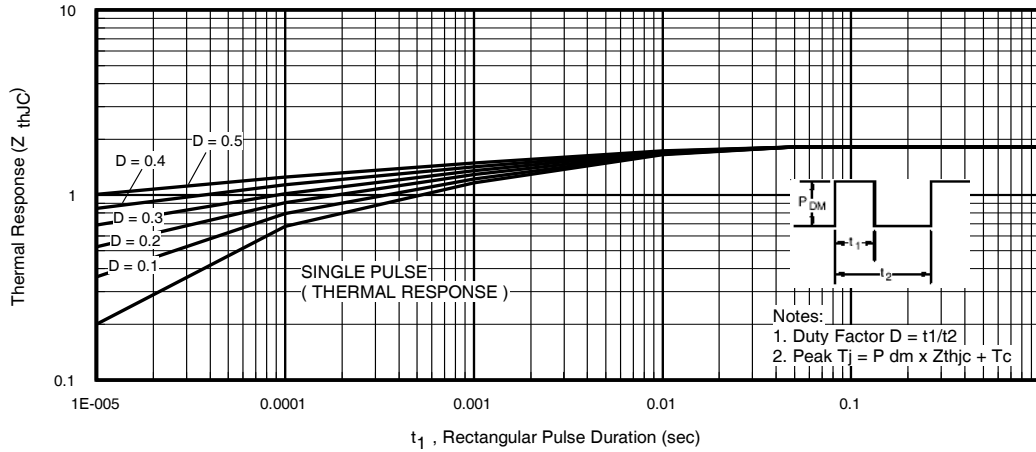


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

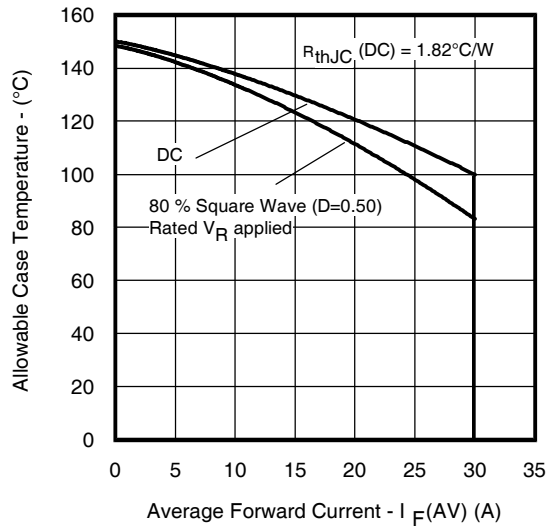


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current